Schottky Barrier Rectifier

5 A, 60 V Low VF

FSV560

Features

- Low Forward Voltage Drop
- Low Thermal Resistance
- Very Low Profile: Typical Height of 1.1 mm
- Green Molding Compound as per IEC61249 Standard
- Non–DAP Option Only
- These Devices are Pb-Free, Halogen Free and are RoHS Compliant

Specifications

ADSOLUTE MAXIMUM INATINGS ($T_A = 25$ C unless otherwise holed)				
Symbol	Parameter	Value	Unit	
V _{RRM}	Peak Repetitive Reverse Voltage	60	V	
V _{RMS}	RMS Reverse Voltage	42	V	
V _R	DC Blocking Voltage	60	V	
I _{F(AV)}	Average Rectified Peak Forward Surge Current at $T_A = 75^{\circ}C$	5	A	
I _{FSM}	Non–Repetitive Peak Forward Surge Current	150	A	
Τ _J	Operating Junction Temperature Range	-55 to +150	°C	
T _{STG}	Storage Temperature Range	-55 to +150	°C	
-	-			

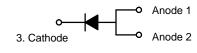
ABSOLUTE MAXIMUM RATINGS ($T_A = 25^{\circ}C$ unless otherwise noted)

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

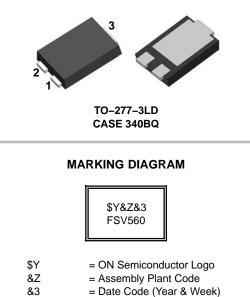


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Schottky Barrier Rectifier



ORDERING INFORMATION

FSV560

= Specific Device Code

See detailed ordering and shipping information on page 2 of this data sheet.

FSV560

THERMAL	THERMAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted) (Note 1)						
Symbol	Characteristic	Minimum Land Pattern	Maximum Land Pattern				
_							

Symbol	Characteristic	Pattern	Pattern	Unit
R _{0JA} Junction-to-Ambient Thermal Resistance		100	40	°C/W
Ψ _{JL} Junction-to-Lead Thermal Characteristics, Thermocouple Soldered to Anode		15	12	°C/W
	Junction-to-Lead Thermal Characteristics, Thermocouple Soldered to Cathode	6	5	

1. The thermal resistances ($R_{0JA} \& \Psi_{JL}$) are characterized with device mounted on the following FR4 printed circuit boards, as shown in Figure 1 and Figure 2. PCB size: 76.2 x 114.3 mm. Minimum land pattern size: 4.9 x 4.8 mm (big pattern, x1), 1.4 x 1.52 mm (small pattern, x2). Maximum land pattern size: 30 x 30 mm (pattern, x2). Force line trace size = 55 mils, sense line trace size = 4 mils.



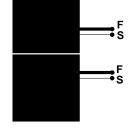
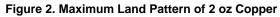


Figure 1. Minimum Land Pattern of 2 oz Copper



ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
BV _R	Breakdown Voltage	I _R = 0.5 mA	60	-	-	V
V _F	Forward Voltage Drop	I _F = 3 A	-	511	-	mV
		I _F = 5 A	-	610	670	
		I _F = 3 A, T _A = 125°C	-	470	-	
		I _F = 5 A, T _A = 125°C	-	560	-	
I _R	Reverse Current	V _R = 48 V	-	12	-	μA
		V _R = 60 V	-	-	150	μA
		V _R = 60 V, T _A = 125°C	-	15	-	mA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

ORDERING INFORMATION

Part Number	Top Mark	Package	Shipping [†]
FSV560	FSV560 TO-277-3LD 5000 / Tape & (Pb-Free/Halogen Free)		5000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

FSV560

TYPICAL PERFORMANCE CHARACTERISTICS

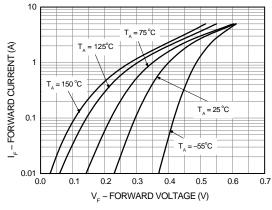


Figure 3. Typical Forward Characteristics

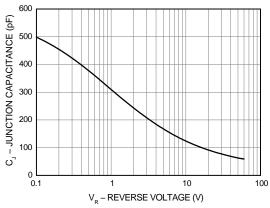


Figure 5. Typical Junction Capacitance

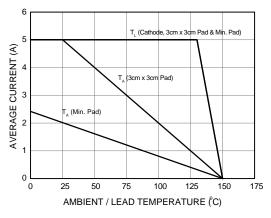


Figure 7. Forward Current Derating Curve

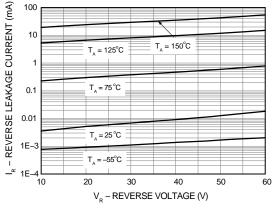


Figure 4. Typical Reverse Characteristics

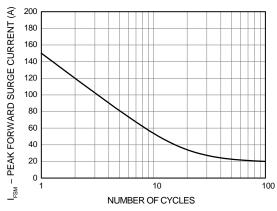
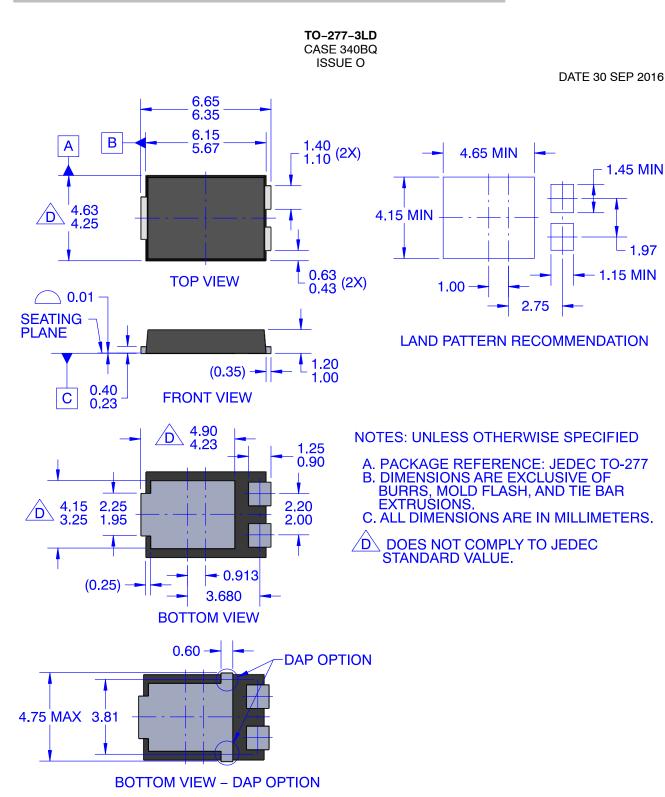


Figure 6. Typical Reverse Characteristic





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DESCRIPTION:	TO-277-3LD		PAGE 1 OF 1	

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